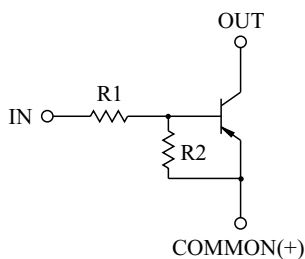


SWITCHING APPLICATION.
INTERFACE CIRCUIT AND DRIVER CIRCUIT APPLICATION.

FEATURES

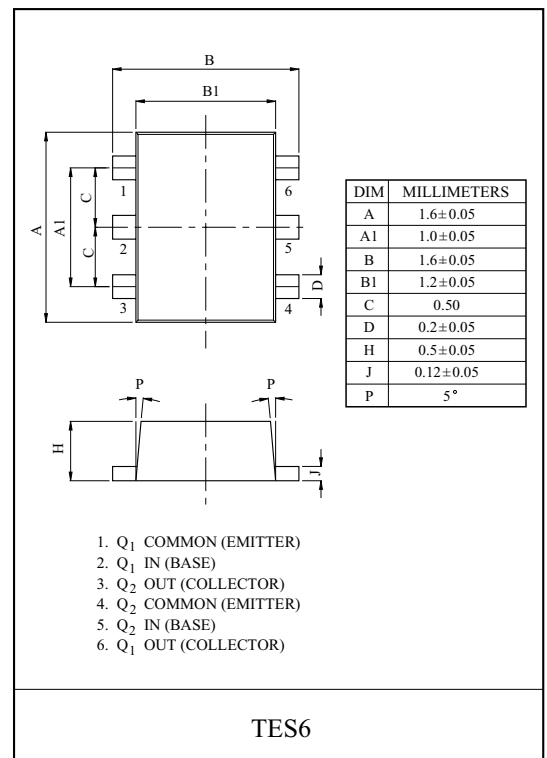
- With Built-in Bias Resistors.
- Simplify Circuit Design.
- Reduce a Quantity of Parts and Manufacturing Process.
- High Packing Density.
- Suffix U : Qualified to AEC-Q101.
ex) KRA757E-RTK/HU

EQUIVALENT CIRCUIT

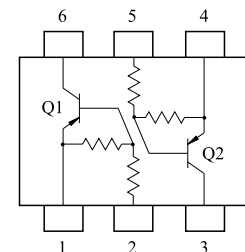


BIAS RESISTOR VALUES

TYPE NO.	R1(k Ω)	R2(k Ω)
KRA757E	10	47
KRA758E	22	47
KRA759E	47	22



EQUIVALENT CIRCUIT (TOP VIEW)



MAXIMUM RATING (Ta=25 °C)

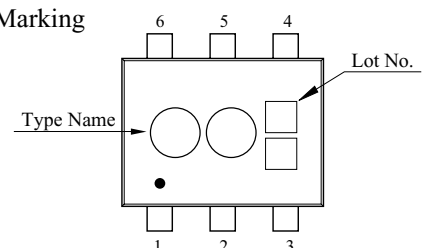
CHARACTERISTIC		SYMBOL	RATING	UNIT
Output Voltage	KRA757E 759E	V _O	-50	V
Input Voltage	KRA757E	V _I	-30, 6	V
	KRA758E		-40, 7	
	KRA759E		-40, 15	
Output Current	KRA757E 759E	I _O	-100	mA
Power Dissipation		P _D *	200	mW
Junction Temperature		T _j	-55~150	
Storage Temperature Range		T _{stg}	-55~150	

* Total Rating.

MARK SPEC

TYPE	KRA757E	KRA758E	KRA759E
MARK	PH	PI	PJ

Marking



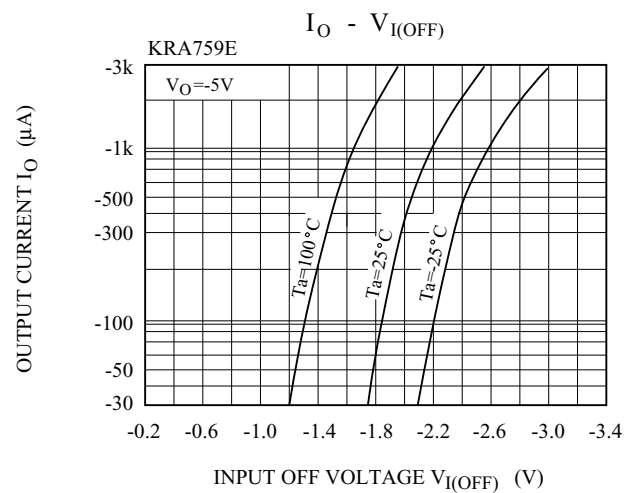
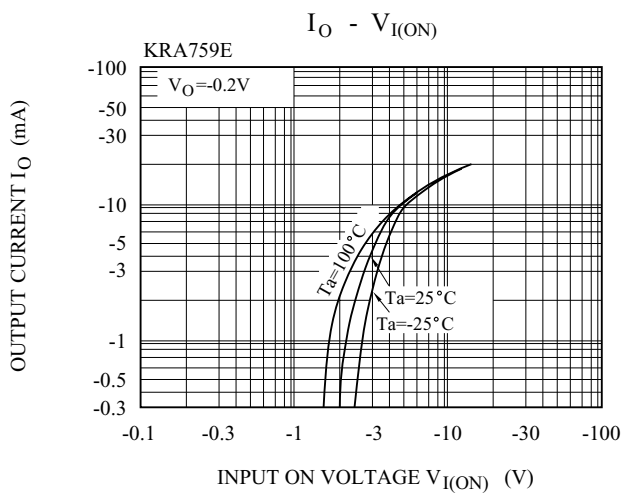
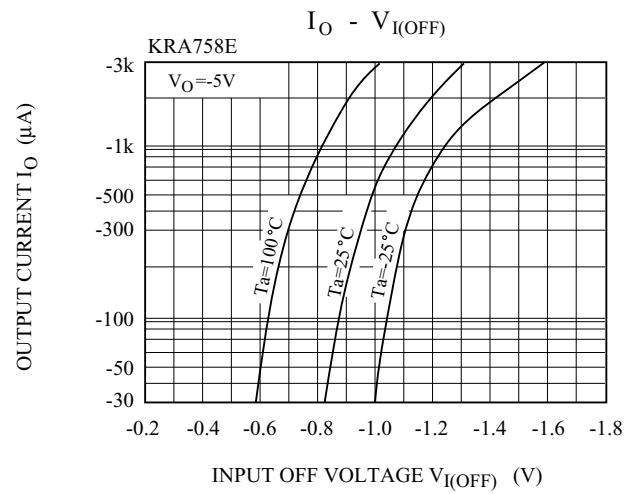
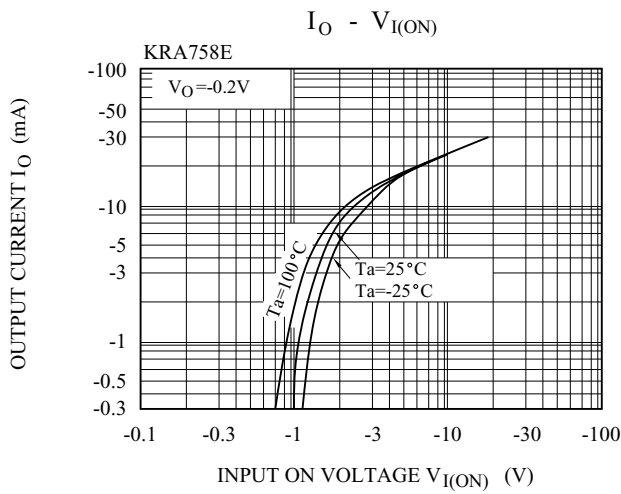
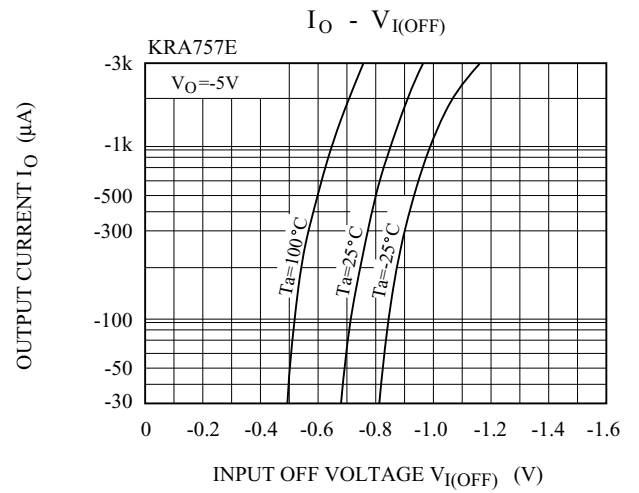
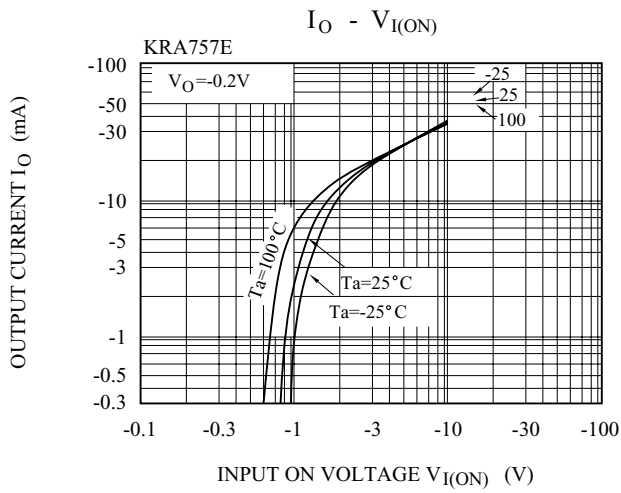
KRA757E~KRA759E

ELECTRICAL CHARACTERISTICS (Ta=25)

CHARACTERISTIC			SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Output Cut-off Current		KRA757E 759E	I _{O(OFF)}	V _O =-50V, V _I =0	-	-	-500	nA
DC Current Gain		KRA757E	G _I	V _O =-5V, I _O =-10mA	80	150	-	
		KRA758E			80	150	-	
		KRA759E			70	140	-	
Output Voltage		KRA757E 759E	V _{O(ON)}	I _O =-10mA, I _I =-0.5mA	-	-0.1	-0.3	V
Input Voltage (ON)		KRA757E	V _{I(ON)}	V _O =-0.2V, I _O =-5mA	-	-1.2	-1.8	V
		KRA758E			-	-1.8	-2.6	
		KRA759E			-	-3.0	-5.8	
Input Votlage (OFF)		KRA757E	V _{I(OFF)}	V _O =-5V, I _O =-0.1mA	-0.5	-0.75	-	V
		KRA758E			-0.6	-0.88	-	
		KRA759E			-1.5	-1.82	-	
Transition Frequency		KRA757E 759E	f _T *	V _O =-10V, I _O =-5mA	-	200	-	MHz
Input Current		KRA757E	I _I	V _I =-5V	-	-	-0.88	mA
		KRA758E			-	-	-0.36	
		KRA759E			-	-	-0.16	
Switching Time	Rise Time	KRA757E	t _r	V _O =-5V, V _{IN} =-5V R _L =1kΩ	-	0.07	-	μs
		KRA758E			-	0.20	-	
		KRA759E			-	0.38	-	
	Storage Time	KRA757E	t _{stg}		-	1.1	-	
		KRA758E			-	1.3	-	
		KRA759E			-	0.7	-	
	Fall Time	KRA757E	t _f		-	0.35	-	
		KRA758E			-	0.4	-	
		KRA759E			-	0.48	-	
Input Resistor		KRA757E	R1	-	7	10	13	kΩ
		KRA758E			15.4	22	28.6	
		KRA759E			32.9	47	61.1	
Resistor Ratio		KRA757E	R2/R1	-	3.7	4.7	5.7	
		KRA758E			1.7	2.1	2.6	
		KRA759E			0.37	0.47	0.57	

Note : * Characteristic of Transistor Only.

KRA757E~KRA759E



KRA757E~KRA759E

